L Number	Hits	Search Text	DB	Time stamp
-	2	("6162715").PN.	USPAT;	2002/11/21 11:53
•			US-PGPUB;	• • •
ł			EPO; JPO;	•
ŀ			DERWENT;	
ľ			IBM TDB	. *
-	23	(tungsten adj nitride or "WN.sub.x") with	USPAT;	2002/11/22 08:35
		(passivating or passivation)	US-PGPUB;	
		.,,	EPO; JPO;	1
			DERWENT;	
			IBM TDB	
_	414	monomethyl adj hydrazine or "MMH"	USPAT;	2002/11/22 07:00
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	407	(tungsten adj nitride or "WN.sub.x") with	USPĀT;	2002/11/22 08:37
		(copper or "cu")	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	64	capacitor and (tungsten adj nitride or	USPAT;	2002/11/22 08:37
5	-	"WN.sub.x") with (copper or "cu")	US-PGPUB;	
ļ		* **	EPO; JPO;	
[DERWENT;	
•			IBM TDB	

L Number	Hits	Search Text	DB	Time stamp
- Number	4640153		USPAT;	2002/11/14 09:28
	101010	polysilicon or aluminum or ferroelectric	US-PGPUB;	•
		or tungsten adj nitride or "W" or "WN" or	EPO; JPO;	•
		"WN.sub.x"	DERWENT;	
			IBM TDB	1
 	9561	diborane or ("b.sub.2" adj "h.sub.6") or	USPAT;	2002/11/14 09:05
	, , ,	"b.sub.2h.sub.6"	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	39933	phosphine or "ph.sub.3"	USPAT;	2002/11/14 09:09
		FINAL TELEVISION OF THE PROPERTY OF THE PROPER	US-PGPUB;	
			EPO; JPO;	
]			DERWENT;	
			IBM TDB	
l -	1226	methylsilane or ("ch.sub.3" adj "si" adj	USPAT;	2002/11/14 09:12
		"h.sub.3") or ("ch.sub.3" adj1	US-PGPUB;	
		"sih.sub.3") or "ch.sub.3sih.sub.3"	EPO; JPO;	ļ
<u> </u>		,	DERWENT;	
			IBM TDB	
_	1226	methylsilane or ("ch.sub.3" adj1 "si" adj1	USPAT;	2002/11/14 09:39
İ		"h.sub.3") or ("ch.sub.3" adj1	US-PGPUB;	
		"sih.sub.3") or "ch.sub.3sih.sub.3"	EPO; JPO;	
		,	DERWENT;	
			IBM TDB	
_	485	hexamethyldisilane	USPAT;	2002/11/14 09:22
		,	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	2245	(diborane or ("b.sub.2" adj "h.sub.6") or	USPAT;	2002/11/14 09:26
		"b.sub.2h.sub.6") with (conductive or	US-PGPUB;	
		metal or tungsten or polysilicon or	EPO; JPO;	
		aluminum or ferroelectric or tungsten adj	DERWENT;	
		nitride or "W" or "WN" or "WN.sub.x")	IBM TDB	
l _	6080		USPĀT;	2002/11/14 09:26
1	0000	or metal or tungsten or polysilicon or	US-PGPUB;	
		aluminum or ferroelectric or tungsten adj	EPO; JPO;	
		nitride or "W" or "WN.sub.x")	DERWENT;	
		interface of it of its of introduction,	IBM TDB	•
_	63	(methylsilane or ("ch.sub.3" adj1 "si"	USPAT;	2002/11/14 09:27
		adj1 "h.sub.3") or ("ch.sub.3" adj1	US-PGPUB;	
		"sih.sub.3") or "ch.sub.3sih.sub.3") with	EPO; JPO;	
		(conductive or metal or tungsten or	DERWENT;	
		polysilicon or aluminum or ferroelectric	IBM_TDB	
		or tungsten adj nitride or "W" or "WN" or		
		"WN.sub.x")		
_	9960	1	USPAT;	2002/11/14 09:30
		("ta.sub.2" adj1 "O.sub. 5") or	US-PGPUB;	
	İ	"ta.sub.20.sub.5"	EPO; JPO;	
	1		DERWENT;	
			IBM TDB	
1 -	6781	tungsten adj nitride or WN or "WN.sub.x"	USPAT;	2002/11/14 09:31
			US-PGPUB;	
			EPO; JPO;	
	ł		DERWENT;	
			IBM TDB	
i -	0	(diborane or ("b.sub.2" adj "h.sub.6") or	USPAT;	2002/11/14 09:34
		"b.sub.2h.sub.6") with (tantalum adj	US-PGPUB;	,
		(oxide or pentoxide) or ("ta.sub.2" adj1	EPO; JPO;	1
		"O.sub. 5") or "ta.sub.2o.sub.5")	DERWENT;	1
1			IBM TDB	
-	0	(methylsilane or ("ch.sub.3" adj1 "si"	USPAT;	2002/11/14 09:34
		adj1 "h.sub.3") or ("ch.sub.3" adj1	US-PGPUB;	
		"sih.sub.3") or "ch.sub.3sih.sub.3") with	EPO; JPO;	
	1	(tantalum adj (oxide or pentoxide) or	DERWENT;	
		("ta.sub.2" adj1 "0.sub. 5") or	IBM TDB	
	1		_	
1	1	"ta.sub.20.sub.5")		

-	5	(phosphine or "ph.sub.3") with (tantalum	USPAT;	2002/11/14 09:34
		adj (oxide or pentoxide) or ("ta.sub.2"	US-PGPUB;	
		adj1 "O.sub. 5") or "ta.sub.2o.sub.5")	EPO; JPO;	•
			DERWENT;	•
			IBM TDB	•
_	0	(methylsilane or ("ch.sub.3" adj1 "si"	USPAT;	2002/11/14 09:34
		adj1 "h.sub.3") or ("ch.sub.3" adj1	US-PGPUB;	
i		"sih.sub.3") or "ch.sub.3sih.sub.3") with	EPO; JPO;	
		(tungsten adj nitride or WN or "WN.sub.x")	DERWENT;	·
:			IBM TDB	
_	3	(diborane or ("b.sub.2" adj "h.sub.6") or	USPAT;	2002/11/14 09:38
		"b.sub.2h.sub.6") with (tungsten adj	US-PGPUB;	
		nitride or WN or "WN.sub.x")	EPO; JPO;	
		,	DERWENT;	
			IBM TDB	
_	2	(phosphine or "ph.sub.3") with (tungsten	USPAT;	2002/11/14 09:37
	_	adj nitride or WN or "WN.sub.x")	US-PGPUB;	
		,	EPO; JPO;	
			DERWENT;	
			IBM TDB	
	6	(methylsilane or ("ch.sub.3" adj1 "si"	USPĀT;	2002/11/14 09:39
		adj1 "h.sub.3") or ("ch.sub.3" adj1	US-PGPUB;	
		"sih.sub.3") or "ch.sub.3sih.sub.3") with	EPO; JPO;	
		conductive	DERWENT;	
			IBM TDB	
			ם מיד ביים דין	1